

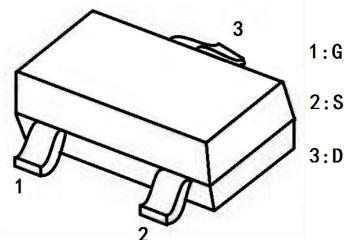
KY2305A

-20V P-Channel Mosfet

FEATURES

- $R_{DS(ON)} \leq 45m\Omega$ (35m Ω Typ.)
@ $V_{GS}=-4.5V$
- $R_{DS(ON)} \leq 70m\Omega$ (38m Ω Typ.)
@ $V_{GS}=-2.5V$
- $R_{DS(ON)} \leq 90m\Omega$ (50m Ω Typ.)
@ $V_{GS}=-1.8V$

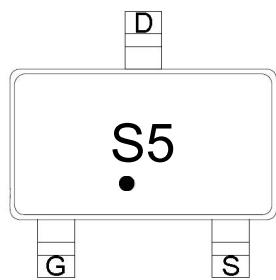
SOT-23



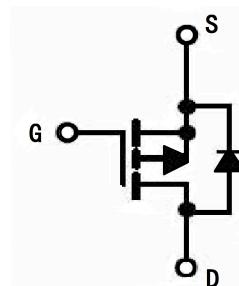
APPLICATIONS

- Load Switch for Portable Devices
- DC/DC Converter

MARKING



P-CHANNEL MOSFET



Other marks: "2305" or "S5B."

Maximum ratings ($T_a=25^\circ C$ unless otherwise noted)

| Symbol | Parameter | Value | Unit |
|-----------------|--|------------|--------------|
| V_{DS} | Drain-Source Voltage | -20 | V |
| V_{GS} | Gate-Source Voltage | ± 12 | |
| I_D | Continuous Drain Current | -4.1 | A |
| I_{DM} | Pulsed Drain Current | -16 | |
| P_D | Maximum Power Dissipation | 0.83 | W |
| $R_{\theta JA}$ | Thermal Resistance from Junction to Ambient($t \leq 5s$) | 150 | $^\circ C/W$ |
| T_J | Junction Temperature | 150 | $^\circ C$ |
| T_{stg} | Storage Temperature | -55 ~ +150 | |

**KY2305A****MOSFET ELECTRICAL CHARACTERISTICS $T_a=25^{\circ}\text{C}$ unless otherwise specified**

| Symbol | Parameter | Test Condition | Min | Typ | Max | Units |
|---------------------------------|---|---|------|-------|-----------|------------------|
| Static | | | | | | |
| $V_{(\text{BR})\text{DSS}}$ | Drain-source breakdown voltage | $V_{GS} = 0V, I_D = -250\mu\text{A}$ | -20 | -21.5 | | V |
| $V_{GS(\text{th})}$ | Gate-source threshold voltage | $V_{DS} = V_{GS}, I_D = -250\mu\text{A}$ | -0.4 | -0.7 | -1 | |
| I_{GSS} | Gate-source leakage | $V_{DS} = 0V, V_{GS} = \pm 10V$ | | | ± 100 | nA |
| I_{DSS} | Zero gate voltage drain current | $V_{DS} = -16V, V_{GS} = 0V$ | | | -1 | μA |
| $R_{DS(\text{on})}$ | Drain-source on-state resistance ^{note1} | $V_{GS} = -4.5V, I_D = -3.5\text{A}$ | | 35 | 45 | $\text{m}\Omega$ |
| | | $V_{GS} = -2.5V, I_D = -3\text{A}$ | | 38 | 70 | |
| | | $V_{GS} = -1.8V, I_D = -2\text{A}$ | | 50 | 90 | |
| V_{SD} | Body diode voltage | $I_S = -3.3\text{A}$ | | -0.9 | -1.2 | V |
| Dynamic ^{note2} | | | | | | |
| C_{iss} | Input capacitance | $V_{DS} = -4V, V_{GS} = 0V, f = 1\text{MHz}$ | | 740 | | pF |
| C_{oss} | Output capacitance | | | 290 | | |
| C_{rss} | Reverse transfer capacitance | | | 190 | | |
| Q_g | Total gate charge | $V_{DS} = -4V, V_{GS} = -2.5V$ $I_D = -4.1\text{A}$ | | 4.5 | 9 | nC |
| Q_{gs} | Gate-source charge | | | 1.2 | | |
| Q_{gd} | Gate-drain charge | | | 1.6 | | |
| $t_{d(on)}$ | Turn-on delay time | $V_{DS} = -4V,$ $R_L = 1.2\Omega, I_D = -3.3\text{A},$ $V_{GEN} = -4.5V, R_G = 1\Omega$ | | 13 | 20 | nS |
| t_r | Rise time | | | 35 | 53 | |
| $t_{d(off)}$ | Turn-off delay time | | | 32 | 48 | |
| t_f | Fall time | | | 10 | 20 | |

Notes: 1. Pulse Test : Pulse Width < 300 μs , Duty Cycle $\leq 2\%$.

2 . Guaranteed by design, not subject to production testing.

Typical Performance Characteristics

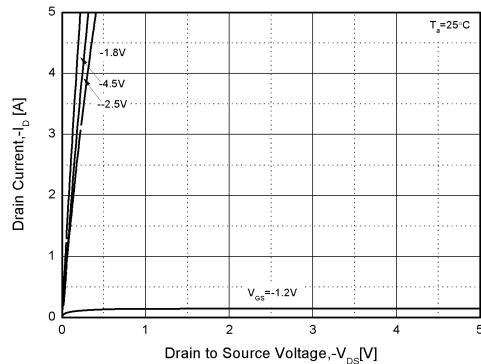


Figure1. Output Characteristics

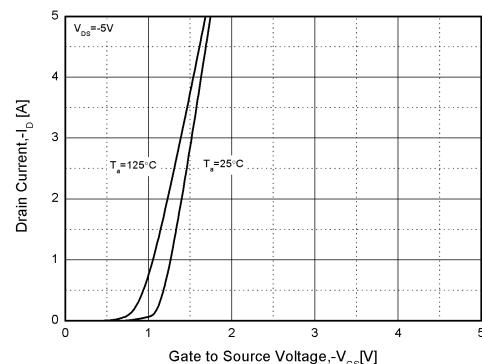


Figure2. Transfer Characteristics

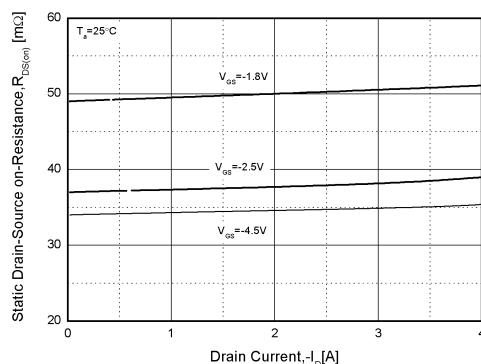


Figure3. R_{DSON} -Drain Current

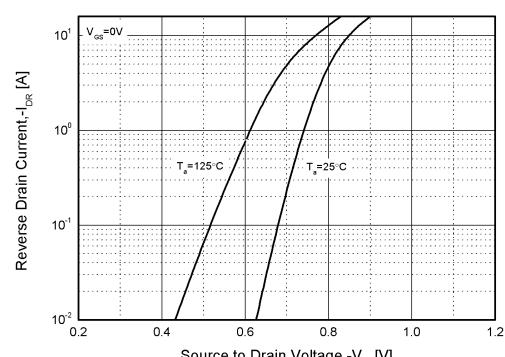


Figure4. Typical Source-Drain Diode Forward Voltage

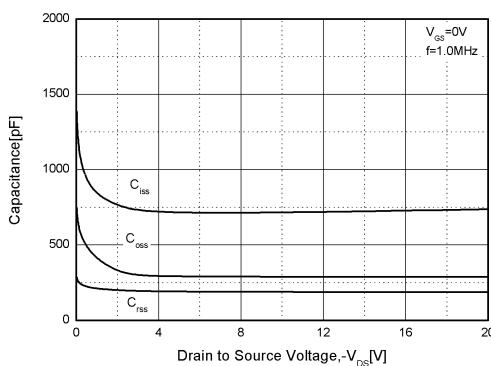


Figure5. Capacitance Characteristics

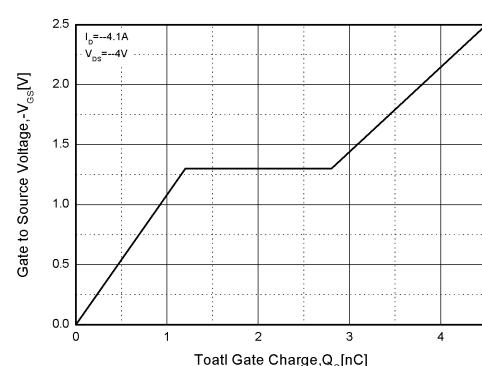


Figure6. Gate Charge

Typical Performance Characteristics (cont.)

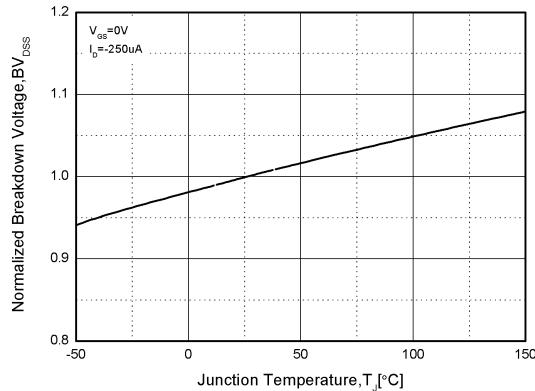


Figure7. Normalized Breakdown Voltage vs. Temperature

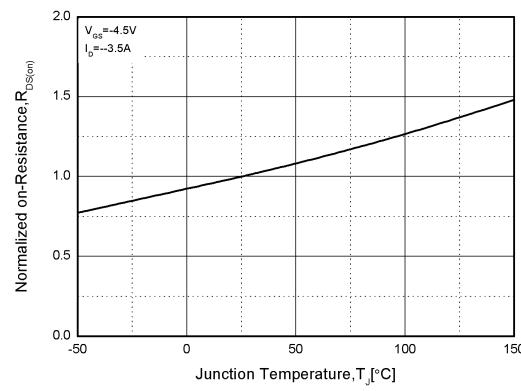


Figure8. Normalized on Resistance vs. Temperature

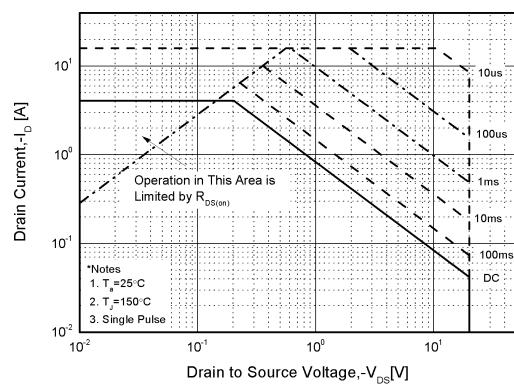


Figure9. Safe Operation Area

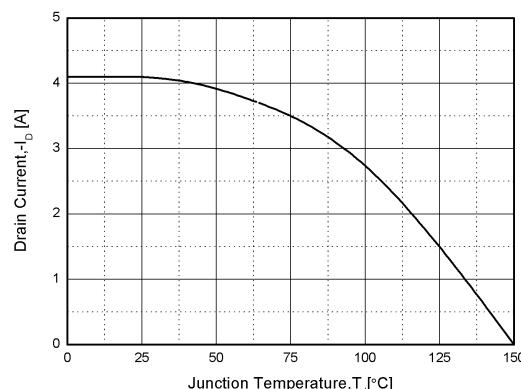
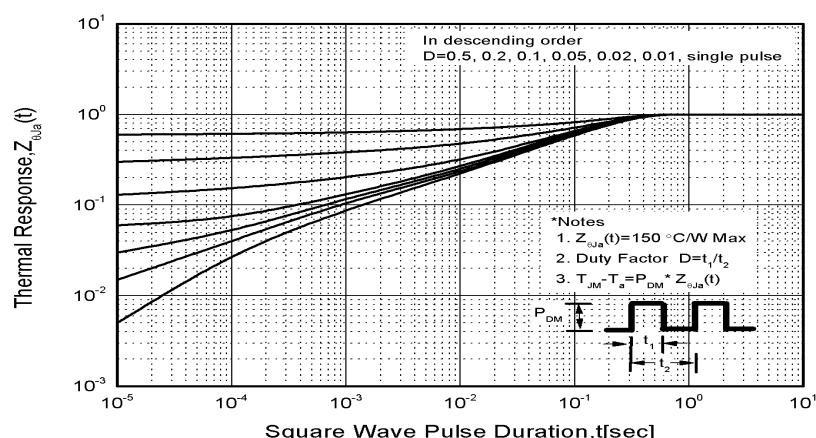
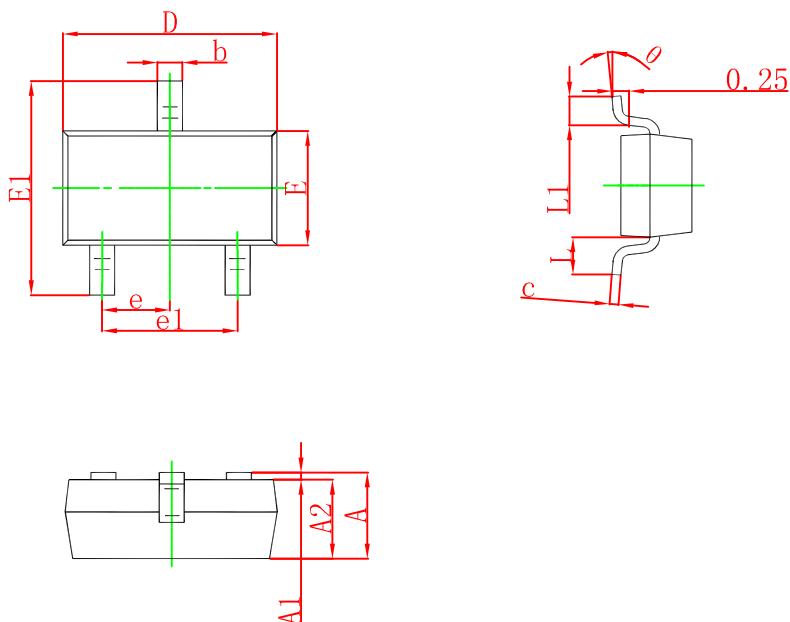


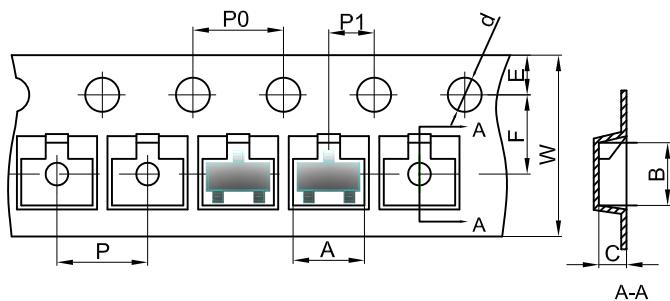
Figure10. Drain Current vs. Case Temperature



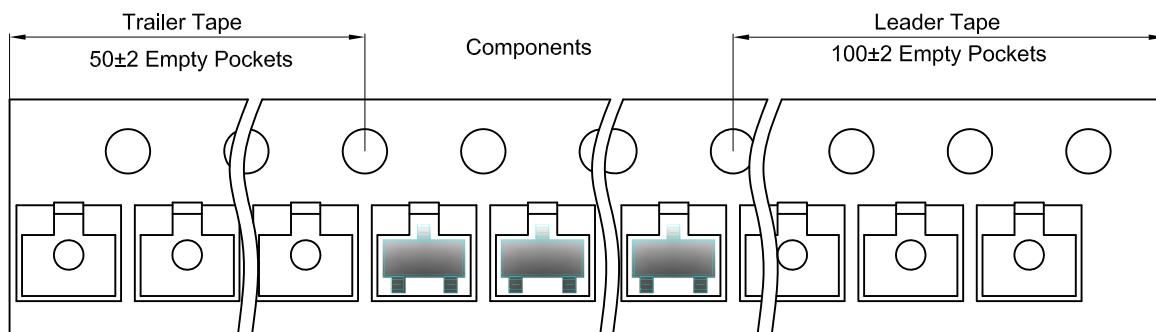
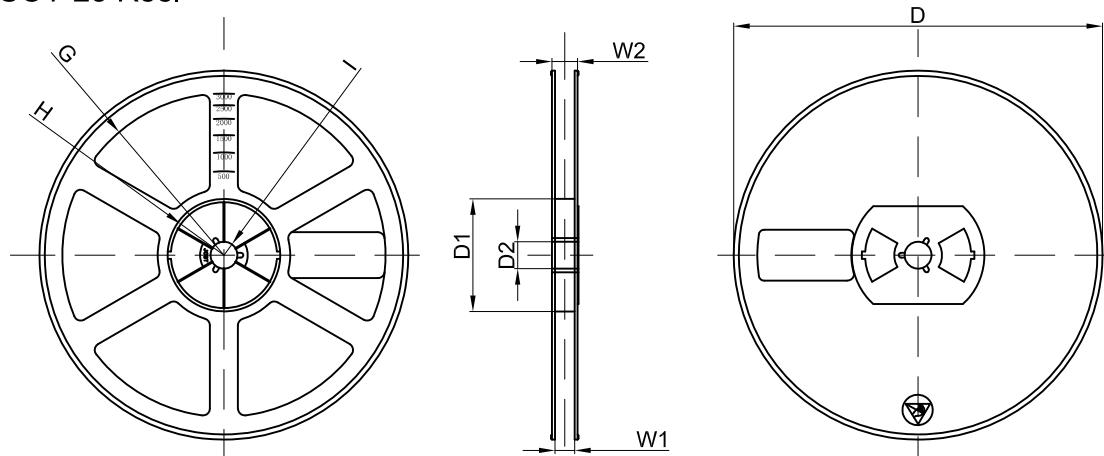
SOT-23 Package Outline Dimensions



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 0.900 | 1.150 | 0.035 | 0.045 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 0.900 | 1.050 | 0.035 | 0.041 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.080 | 0.150 | 0.003 | 0.006 |
| D | 2.800 | 3.000 | 0.110 | 0.118 |
| E | 1.200 | 1.400 | 0.047 | 0.055 |
| E1 | 2.250 | 2.550 | 0.089 | 0.100 |
| e | 0.950 TYP | | 0.037 TYP | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.550 REF | | 0.022 REF | |
| L1 | 0.300 | 0.500 | 0.012 | 0.020 |
| θ | 0° | 8° | 0° | 8° |

SOT-23 Embossed Carrier Tape


| Dimensions are in millimeter | | | | | | | | | | |
|------------------------------|------|------|------|-------|------|------|------|------|------|------|
| Pkg type | A | B | C | d | E | F | P0 | P | P1 | W |
| SOT-23 | 3.15 | 2.77 | 1.22 | Ø1.50 | 1.75 | 3.50 | 4.00 | 4.00 | 2.00 | 8.00 |

SOT-23 Tape Leader and Trailer

SOT-23 Reel


| Dimensions are in millimeter | | | | | | | |
|------------------------------|---------|-------|-------|--------|--------|-------|------|
| Reel Option | D | D1 | D2 | G | H | I | W1 |
| 7" Dia | Ø178.00 | 54.40 | 13.00 | R78.00 | R25.60 | R6.50 | 9.50 |

| REEL | Reel Size | Box | Box Size(mm) | Carton | Carton Size(mm) | G.W.(kg) |
|----------|-----------|------------|--------------|-------------|-----------------|----------|
| 3000 pcs | 7 inch | 45,000 pcs | 203×203×195 | 180,000 pcs | 438×438×220 | |